MOSFET - P-Channel Logic

Level PowerTrench®

-40 V, 13.5 mΩ, -50 A

FDD9510L-F085

Features

- Typ $R_{DS(on)} = 11 \text{ m}\Omega$ at $V_{GS} = -10 \text{ V}$; $I_D = -50 \text{ A}$
- Typ $Q_{g(tot)} = 28 \text{ nC}$ at $V_{GS} = -10 \text{ V}$; $I_D = -50 \text{ A}$
- UIS Capability
- Qualified to AEC Q101
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electrical Power Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12 V Systems

ABSOLUTE MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	-40	V
Gate to Source Voltage	V _{GS}	±16	V
Drain Current – Continuous (V _{GS} = -10 V) (T _C = 25°C) (Note 1)	lp	_50	A
Pulsed Drain Current (T _C = 25°C)		See Figure 4	Α
Single Pulse Avalanche Energy (Note 2)	E _{AS}	35.3	mJ
Power Dissipation	PD	75	W
Derate above 25°C	P _D	0.5	W/°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C
Thermal Resistance (Junction to Case)	$R_{\theta JC}$	2	°C/W
Maximum Thermal Resistance (Junction to Ambient) (Note 3)	$R_{\theta JA}$	52	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

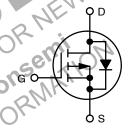
- 1. Current is limited by wirebond configuration
- 2. Starting Tj = 25°C, L = 40 μ H, I_{AS} = -42 A, V_{DD} = -40 V during inductor charging and V_{DD} = 0 V during time in avalanche
- 3. R_{B.IA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2 oz copper.



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ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Reel Size	Tape Width	Quantity
FDD9510L-F085	FDD9510L	D-PAK (TO-252)	13″	16 mm	2500 Units

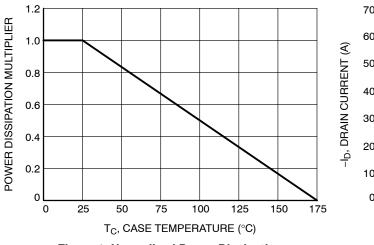
ELECTRICAL CHARACTERISTICS (T_{.J} = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
OFF CHARACT	TERISTICS	•				•	
BV _{DSS}	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-40	_	-	V
I _{DSS}	Drain to Source Leakage Current	$V_{DS} = -40 \text{ V},$ $V_{GS} = 0 \text{ V}$	T _J = 25°C	_	_	-1	μΑ
			T _J = 175°C (Note 4)	_	-	-1	mA
I_{GSS}	Gate to Source Leakage Current	V _{GS} = ±16 V		-	-	±100	nA
N CHARACTE	ERISTICS						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		-1	-1.9	-3	V
R _{DS(on)}	Drain to Source On-Resistance	$V_{GS} = -4.5 \text{ V}, I_{C}$	₀ = -50 A, T _J = 25°C	-	16	22	mΩ
		V _{GS} = -10 V,	T _J = 25°C		11	13.5	mΩ
		I _D = -50 A	T _J = 175°C (Note 4)	_	18	22.7	$m\Omega$
YNAMIC CHA	ARACTERISTICS			NE	1		
C _{iss}	Input Capacitance	$V_{DS} = -20 \text{ V}, V_{C}$	as = 0 V, f = 1 MHz	-	2020	-	pF
C _{oss}	Output Capacitance		ŁO.	O.FILI	785	-	pF
C _{rss}	Reverse Transfer Capacitance		SED O	5-1	36	-	pF
R _g	Gate Resistance	$V_{GS} = -0.5 \text{ V, f}$	= 1 MHz	MIL	23	-	Ω
Q _{g(tot)}	Total Gate Charge	$V_{DD} = -20 \text{ V},$	$V_{GS} = 0 \text{ V to } -10 \text{ V}$	_	28	37	nC
$Q_{g(-4.5)}$	Total Gate Charge	$I_{\rm D} = -50 {\rm A}$	$V_{GS} = 0 \text{ V to } -4.5 \text{ V}$	_	13	-	nC
Q _{g(th)}	Threshold Gate Charge	SCO DC	V _{GS} = 0 V to -1 V	_	2	-	nC
Q_{gs}	Gate to Source Gate Charge	$V_{DD} = -20 \text{ V}, I_D$	= -50 A	_	7	-	nC
Q_{gd}	Gate to Drain "Miller" Charge	10,"11k		_	4	-	nC
WITCHING CH	HARACTERISTICS C	TAIL					
t _{on}	Turn-On Time	$V_{DD} = -20 \text{ V, } I_{D}$	= -50 A,	_	_	44	ns
t _{d(on)}	Turn-On Delay Time	$V_{GS} = -10 \text{ V, R}_0$	GEN = 6 Ω	_	8	-	ns
t _r	Turn-On Rise Time			_	21	-	ns
t _{d(off)}	Turn-Off Delay Time			_	113	-	ns
tf	Turn-Off Fall Time			-	35	-	ns
t _{off}	Turn-Off Time			-	_	220	ns
RAIN-SOUR	CE DIODE CHARACTERISTICS						
V _{SD}	Source to Drain Diode Voltage	V _{GS} = 0 V, I _{SD} =	= -50 A	-	-0.97	-1.25	V
		V _{GS} = 0 V, I _{SD} =	= –25 A	-	-0.9	-1.2	V
T _{rr}	Reverse Recovery Time	$I_F = -50 \text{ A, dI}_{SD}$	/dt = 100 A/μs	-	42	63	ns
Q _{rr}	Reverse Recovery Charge			_	31	56	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production

TYPICAL CHARACTERISTICS



70 Current Limited by Package 60 50 40 30 20 V_{GS} = -10 V 10 0 75 100 125 150 25 175 T_C, CASE TEMPERATURE (°C)

Figure 1. Normalized Power Dissipation vs.

Case Temperature

Figure 2. Maximum Continuous Drain Current vs. Case Temperature

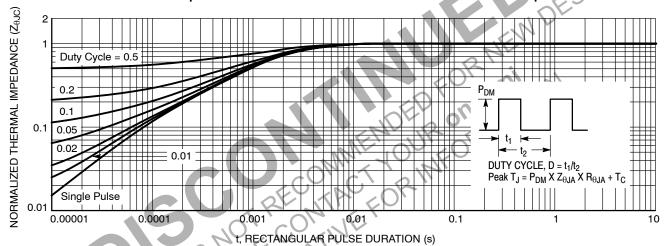


Figure 3. Normalized Maximum Transient Thermal Impedance

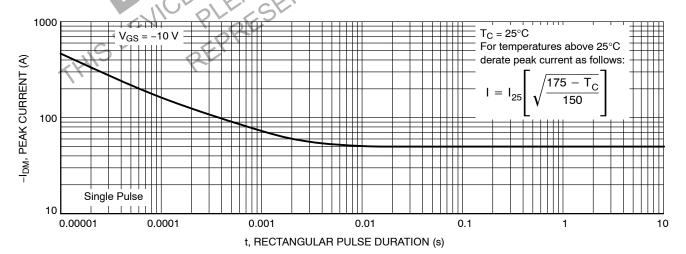
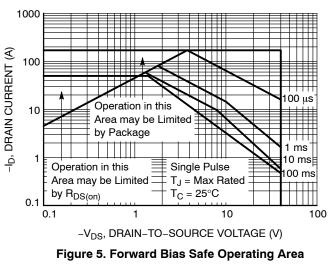


Figure 4. Peak Current Capability

TYPICAL CHARACTERISTICS



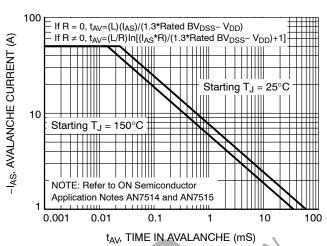


Figure 6. Unclamped Inductive Switching Capability

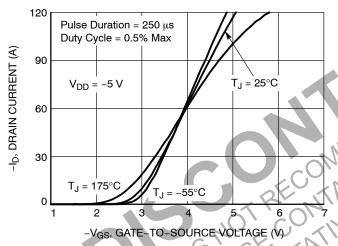


Figure 7. Transfer Characteristics

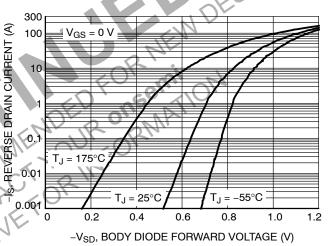


Figure 8. Forward Diode Characteristics

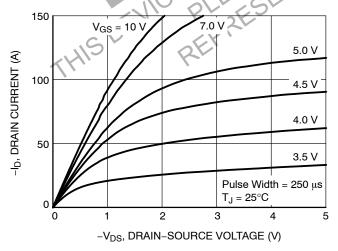


Figure 9. Saturation Characteristics

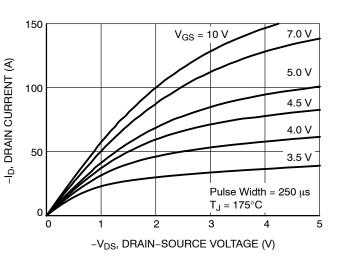
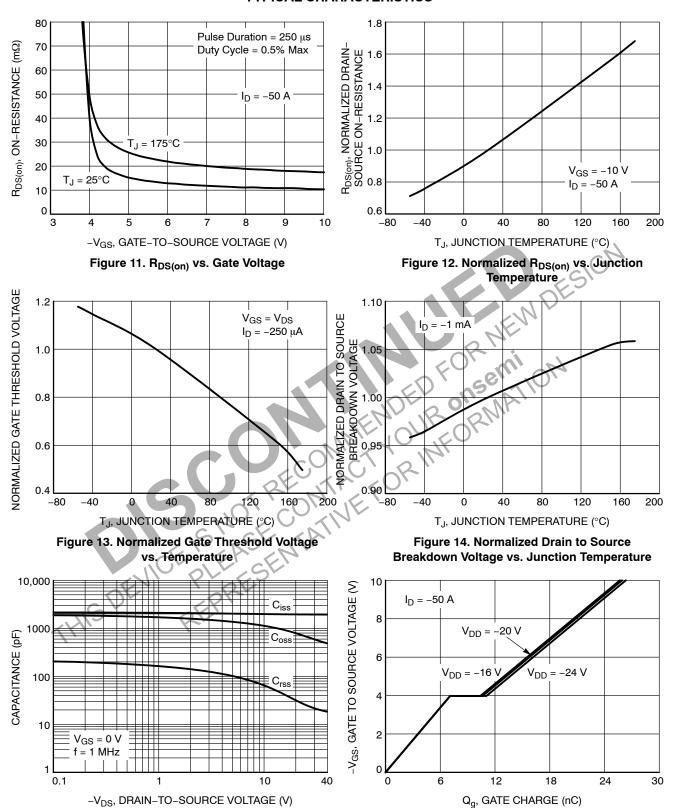


Figure 10. Saturation Characteristics

TYPICAL CHARACTERISTICS



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Figure 15. Capacitance vs. Drain to Source

Voltage

Figure 16. Gate Charge vs. Gate to Source

Voltage





DPAK3 6.10x6.54x2.29, 4.57P CASE 369AS **ISSUE B**

DATE 20 DEC 2023

- NOTES: UNLESS OTHERWISE SPECIFIED

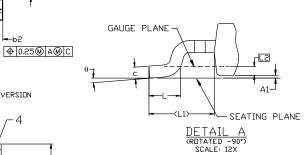
 A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE F, VARIATION AA.

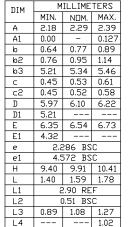
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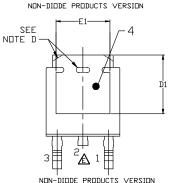
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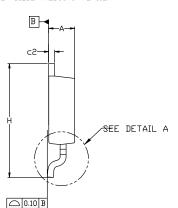
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- DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M-2018.
 SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED
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 LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD
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LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*

10°

XXXXXX XXXXXX **AYWWZZ**

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXXX = Specific Device Code

= Assembly Location Α

Υ = Year

WW = Work Week

77 = Assembly Lot Code

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